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(703) 872-9306U.S. Application No.:
10/730,995

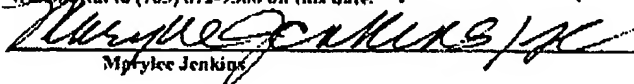
Attorney Docket No.: 103213/00065 Group Art Unit: 2811

Hard Copy Sent: No Examiner: Hung K. Vu

Comments:

We are forwarding herewith a Facsimile Transmittal Cover Sheet, an "Amendment under 37 C.F.R. § 1.116," in the application of Hidetoshi NISHIKAWA, et al., U.S. Serial No. 10/730,995 for MOSFET FOR AN OPEN-DRAIN CIRCUIT AND SEMICONDUCTOR INTEGRATED CIRCUIT DEVICE EMPLOYING IT filed December 10, 2003 in Group 2811.

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Marylee JenkinsApril 7, 2005
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APR 7 2005

PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:

Hidetoshi NISHIKAWA et al.

Group Art Unit: 2811

Serial No.: 10/730,995

Examiner: Hung K. Vu

Filed: December 10, 2003

Docket No.: 103213-00065

For: MOSFET FOR AN OPEN-DRAIN CIRCUIT AND SEMICONDUCTOR
INTEGRATED CIRCUIT DEVICE EMPLOYING ITAMENDMENT UNDER 37 C.F.R. § 1.116Commissioner for Patents
P.O. Box 1450
Alexandria, Virginia 22313-1450

Dated: April 7, 2005

Introductory Comments

Sir:

In response to the Office Action mailed January 11, 2005, please amend the above-
identified application as set forth below.

Amendments to the Claims begin on Page 2.

Remarks begin on Page 6.

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Mark Jenkins